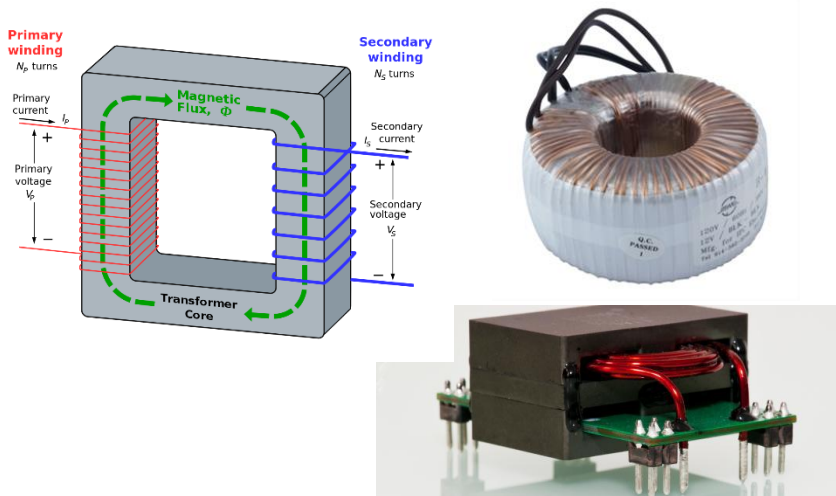

A Systematic Approach to Modeling Impedances and Current Distribution in Planar Magnetics

**Minjie Chen¹, Mohammad Araghchini¹, Khurram K. Afridi², Jeffrey H. Lang¹
Charles R. Sullivan³ and David J. Perreault¹**

1. Massachusetts Institute of Technology
2. University of Colorado Boulder
3. Dartmouth College

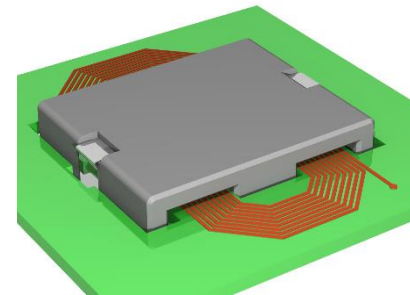
November 5, 2014

Magnetics with wire windings

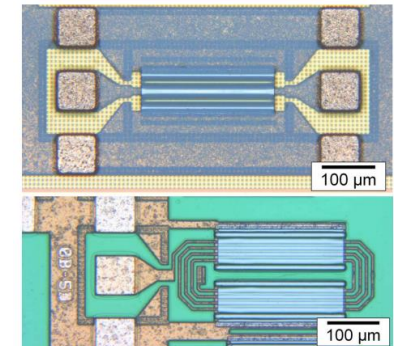
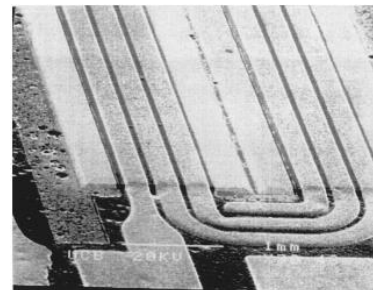


Magnetics with planar windings

on PCB



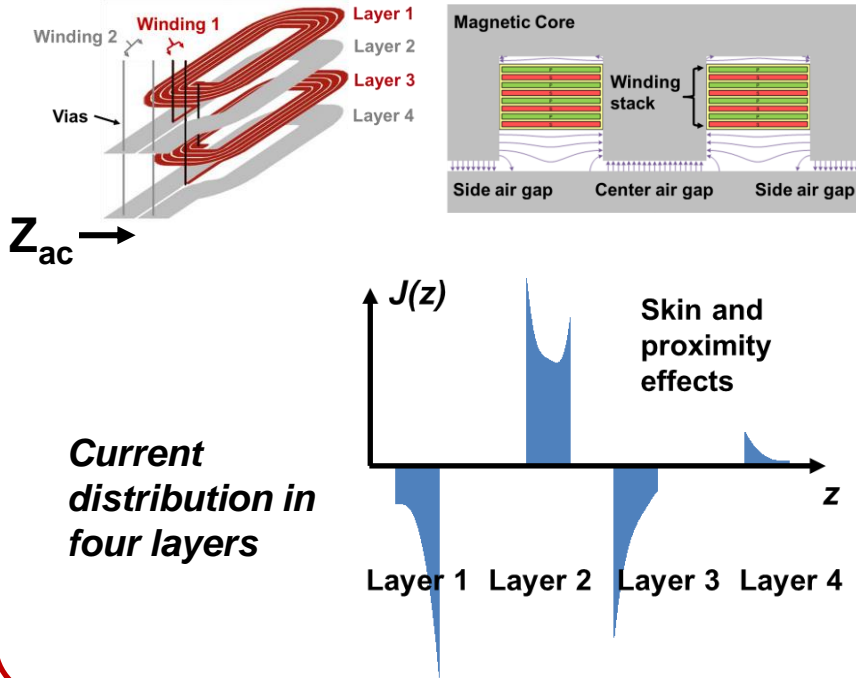
on Chip



Advantages of Planar Magnetics:

1. High repeatability
2. Suitable for high frequency
3. Good thermal performance
4. High power density

- L. Daniel, "Design of microfabricated inductors", *IEEE Trans. Power Electron.*, 1999
- D.S. Gardner, "Review of on-chip inductor structures with magnetic films", *IEEE Trans. Magn.*, 2009



1. *Skin- and proximity- effects makes the modeling challenging.*

2. *Solving Maxwell's equations for all design options is not practical.*

3. *Existing analytical models usually have specific assumptions and are not easy to use.*

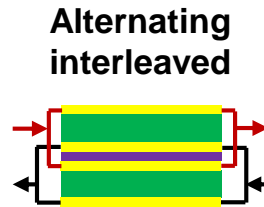
4. *Finite element modeling are:*

- Time consuming
- Not analytical

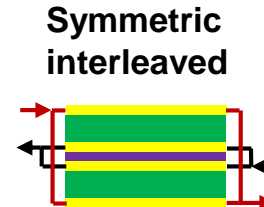
An analytical approach that is:

Accurate Fast Easy to Use Widely Applicable

1. What is the most appropriate way to interleave many layers?

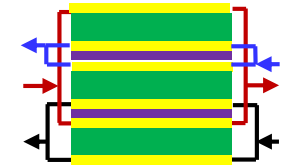


1 & 3 in parallel
2 & 4 in parallel



1 & 4 in parallel
2 & 3 in parallel

More complicated?



...?

2. What is the most appropriate PCB spacing?

Thin Middle Spacing Thick Middle Spacing



3. Other Design Options?

- 1) Leakage & Shielding Layers?
- 2) Hybrid Materials (Ni/Cu/FR4)?
- 3) Multi-Resonant Devices?
- 4) Etc...?

Every model starts from assumptions ...

(1) MQS assumption

- Assume $\frac{\partial E}{\partial t} = 0$.
- Applicable when the wavelength is much longer than the device size (usually lower than $\sim 100\text{MHz}$).

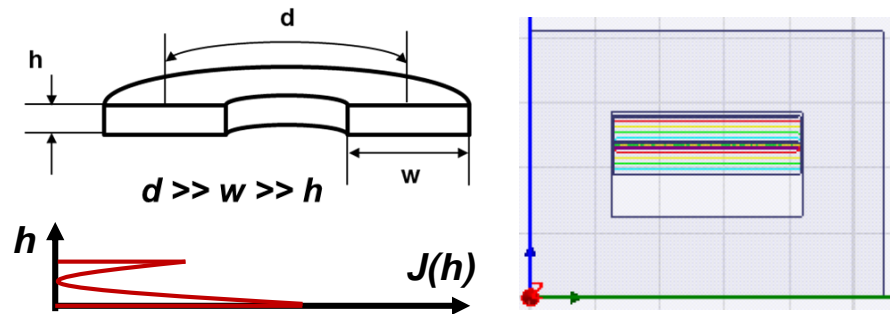
Magneto-Quasi-Static Maxwell's equations

$$\left\{ \begin{array}{l} \nabla E = \frac{\rho}{\epsilon_0} \\ \nabla B = 0 \\ \nabla \times E = -\frac{\partial B}{\partial t} \\ \nabla \times B = \mu_0 \left(J + \epsilon_0 \frac{\partial E}{\partial t} \right) \end{array} \right. \quad \text{Ignore the time evolution of the electric field}$$

(2) 1-D assumption

- Fields vary only along the thickness direction.
- Applicable when the flux is guided by the magnetic core.

Magnetic core guides the flux



Skin and proximity effects change current distribution

Field diffusion equations:

$$H_X(z) = \frac{H_T \sinh(\Psi z) + H_B \sinh(\Psi(h - z))}{\sinh(\Psi h)}$$

Ampere's law:

$$\nabla \times H = J = \sigma E \quad \Psi = \frac{1+j}{\delta} \quad \delta = \sqrt{\frac{2}{\mu\omega\sigma}}$$

E field as a function of H and K:

$$\begin{cases} E_T = E_Y(h) = \frac{\Psi}{\sigma} \left(\frac{H_T e^{\Psi h} - H_B}{e^{\Psi h} - e^{-\Psi h}} - \frac{H_B - H_T e^{-\Psi h}}{e^{\Psi h} - e^{-\Psi h}} \right) \\ E_B = E_Y(0) = \frac{\Psi}{\sigma} \left(\frac{H_T - H_B e^{-\Psi h}}{e^{\Psi h} - e^{-\Psi h}} - \frac{H_B e^{\Psi h} - H_T}{e^{\Psi h} - e^{-\Psi h}} \right) \end{cases} \quad \begin{cases} Z_a = \frac{\Psi(1 - e^{-\Psi h})}{\sigma(1 + e^{-\Psi h})} \\ Z_b = \frac{2\Psi e^{-\Psi h}}{\sigma(1 - e^{-2\Psi h})} \end{cases}$$

KVL/KCL relationships:

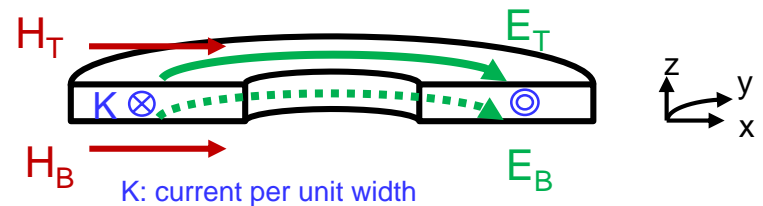
V/m Ω A/m

$$\begin{cases} E_T = Z_a H_T + Z_b K \\ E_B = Z_b K - Z_a H_B \\ K = H_T - H_B \end{cases}$$

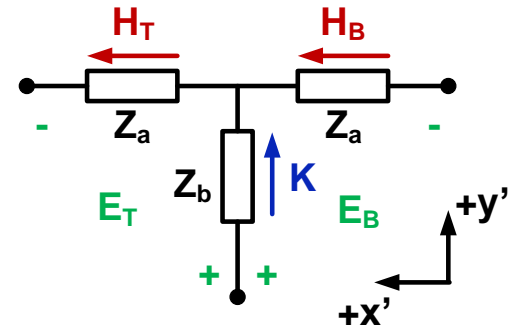
KVL
KVL
KCL

H & K: through variables ~ unit (A/m)
E: across variable ~ unit (V/m)
Z_a, Z_b: impedances ~ unit (Ω)

Electromagnetic Fields



Modular Layer Model



Intuition:

- Two three-terminal networks
- Connected by the H field between them

Faraday's Law and Field Continuity

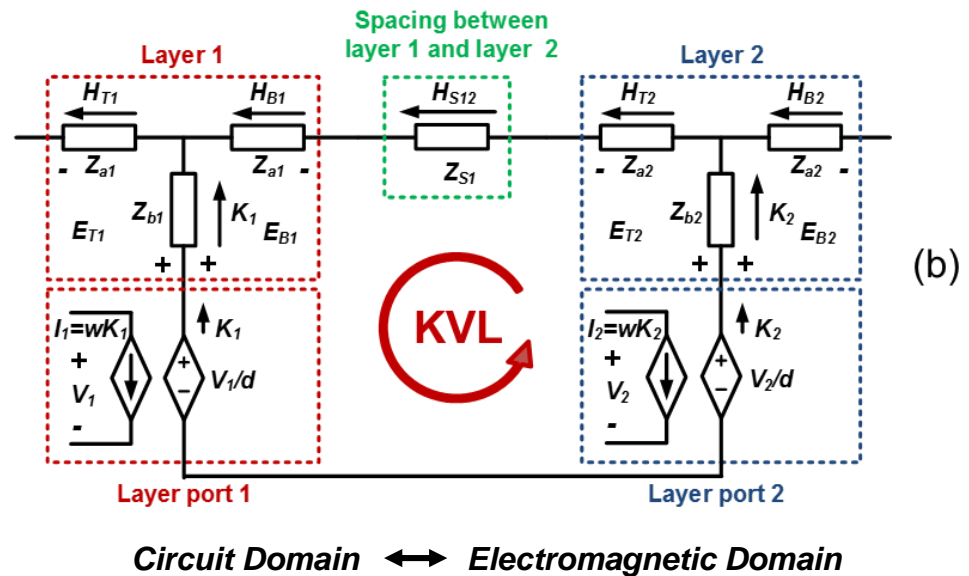
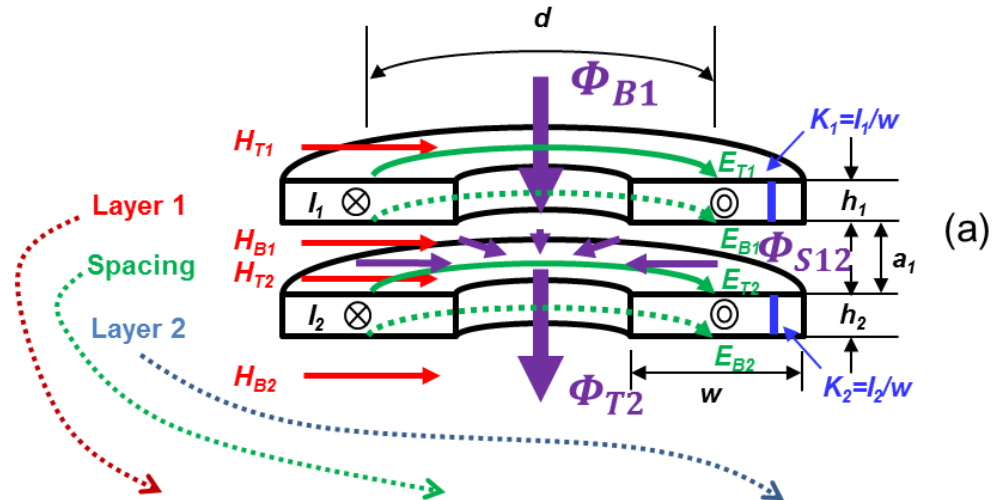
$$E_{B1}d - V_1 = -\frac{d\Phi_{B1}}{dt} \quad E_{T2}d - V_2 = -\frac{d\Phi_{T2}}{dt}$$

$$\frac{d\Phi_{T2}}{dt} = \frac{d\Phi_{B1}}{dt} + \frac{d\Phi_A}{dt}$$

Flux Linking Two Layers:

An additional KVL equation

$$\underbrace{j\omega\mu_0 a_1}_{\Omega} \underbrace{H_{S12}}_{A/m} = \underbrace{\frac{V_2}{d} - E_{T2} - \frac{V_1}{d} + E_{B1}}_{V/m}$$

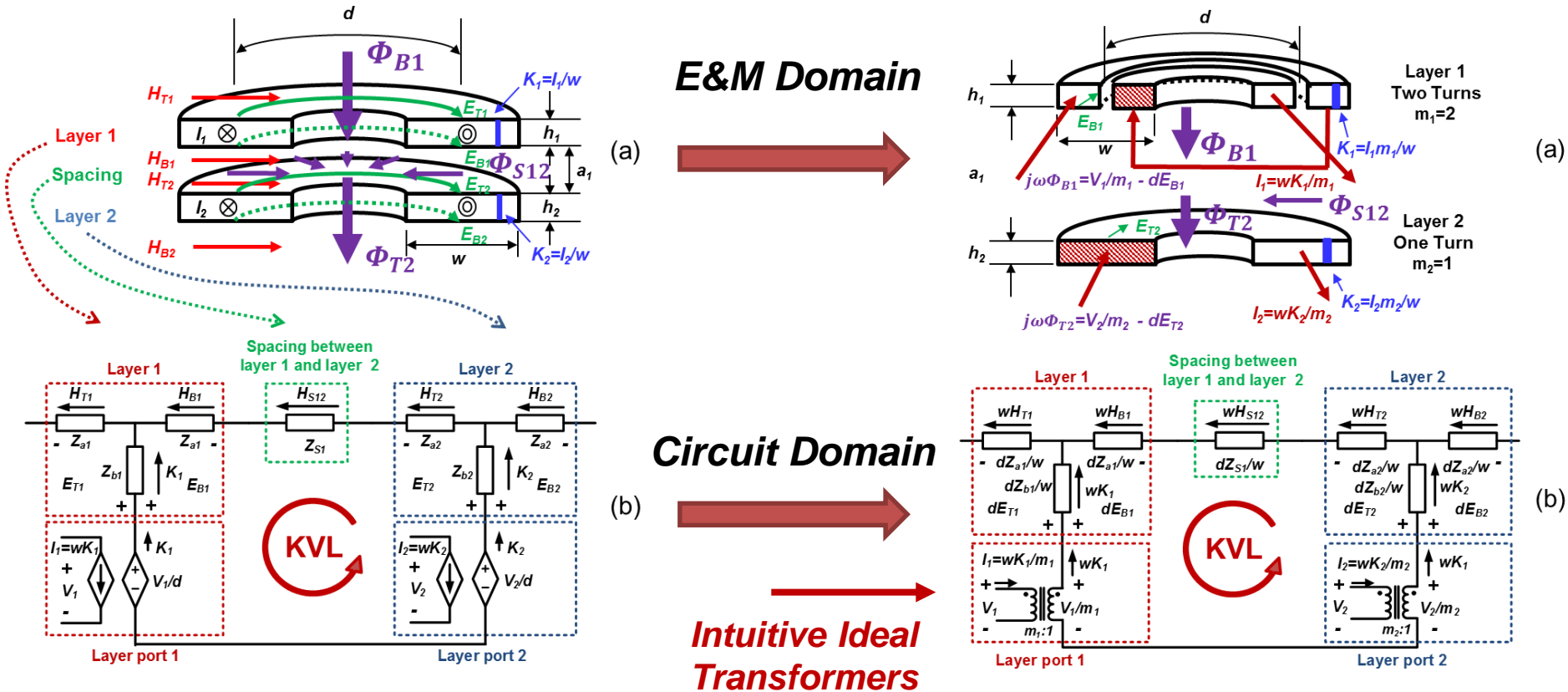


Modeling Layers with Multiple Turns



Fields distributions in multiple-turns layers are linearly related to those in single-turn layers

Multiple turns \rightarrow Additional Linear Conversions



Modeling n Layers, the Core and the Air Gap



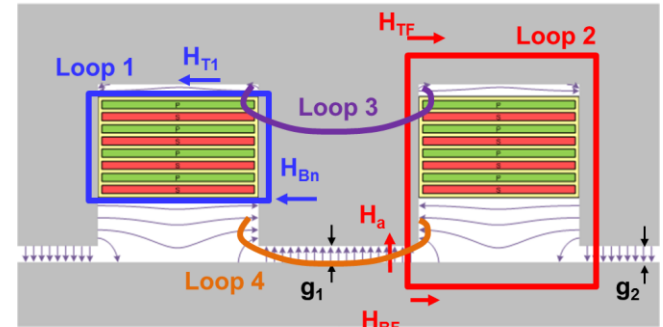
Additional Impedances Representing the Cores and Air Gaps

1. Top Side

$$E_{T1} - \frac{V_1}{d} = -j\omega\mu_r c H_{T1} - j\omega\mu_0 b H_{T1}$$

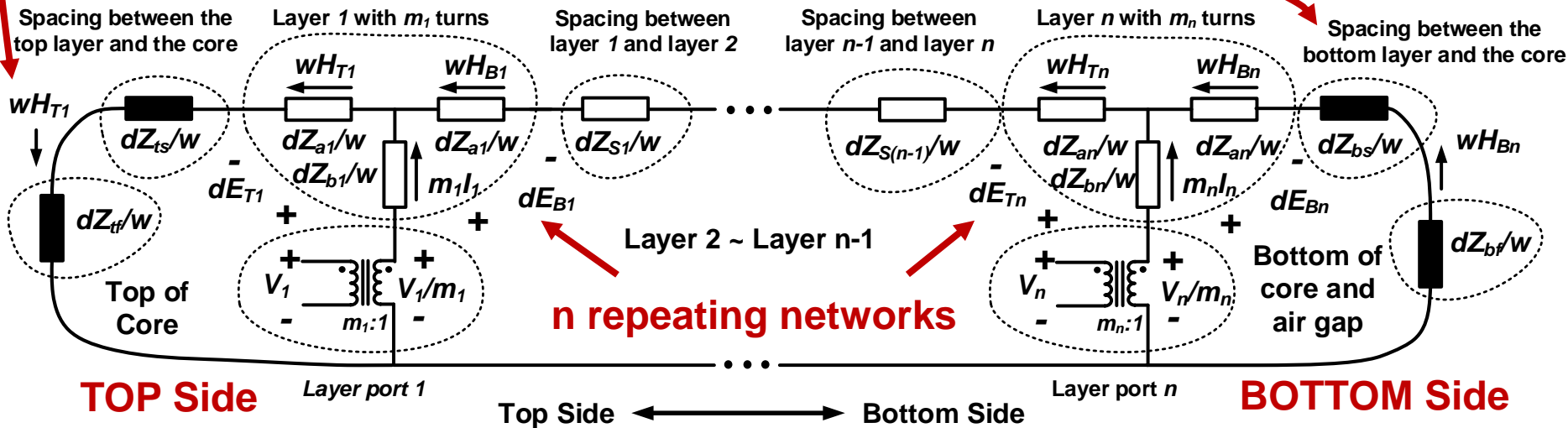
2. Bottom Side

$$E_{Bn} - \frac{V_n}{d} = j\omega \frac{\mu_0 A_c w}{(g_1 + g_2 + \frac{\mu_0 A_c w}{\mu_r c d}) d} H_{Bn} + j\omega\mu_0 b H_{Bn}$$



TOP Side

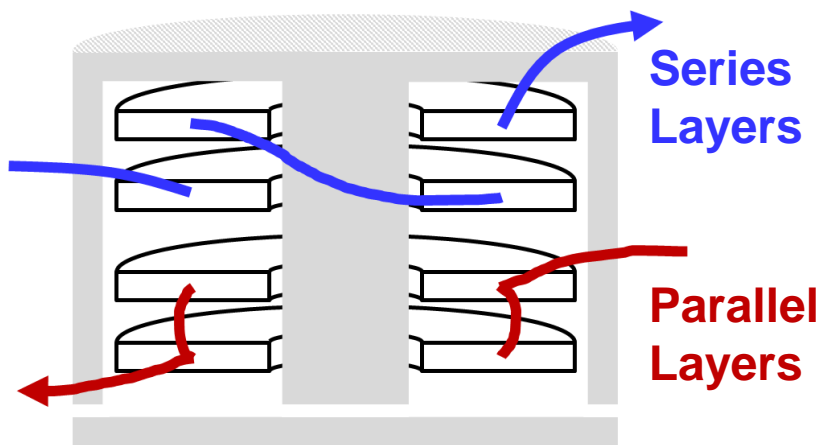
BOTTOM Side



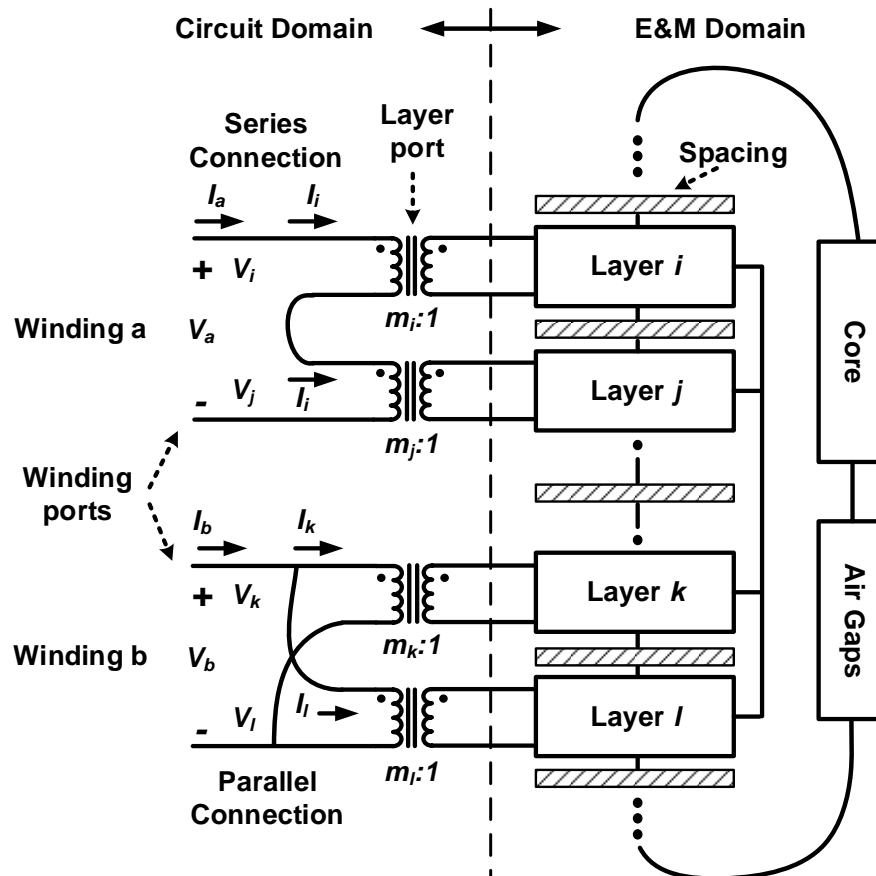
Modeling vias is equivalent to adding KVL, KCL constraints:

Layer i and Layer j in series
 Layer k and Layer l in parallel

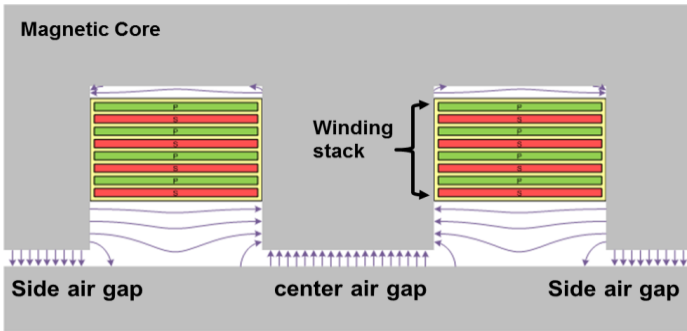
$$\begin{cases} V_i + V_j = V_a \\ V_k = V_l = V_b \end{cases} \quad \begin{cases} I_i = I_j = I_a \\ I_k + I_l = I_b \end{cases}$$



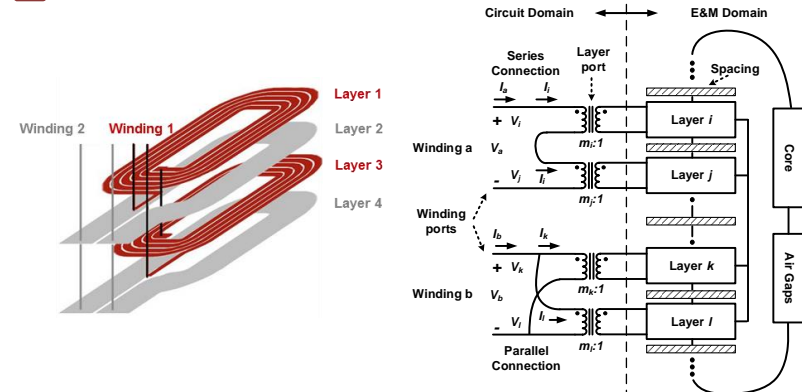
Connect the layer ports in the same pattern as they are in the real circuit



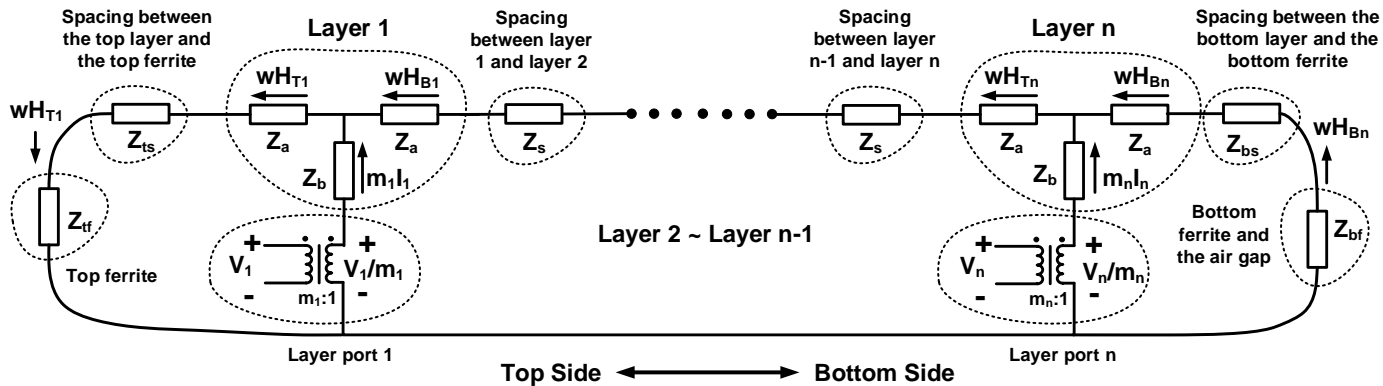
1 Geometry Information



3 Cross Layer Connections



2 Modular Layer Model

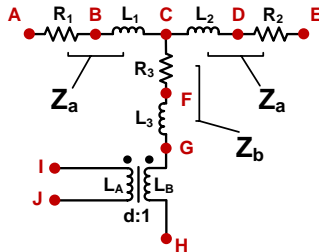
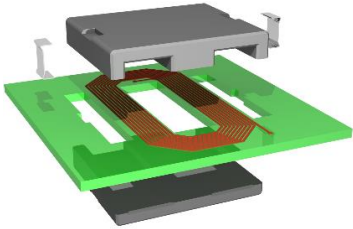


Use the model!

Use the Model Numerically

Netlist generation and full circuit simulation

Geometry → Impedances → Netlists → Simulations (SPICE)

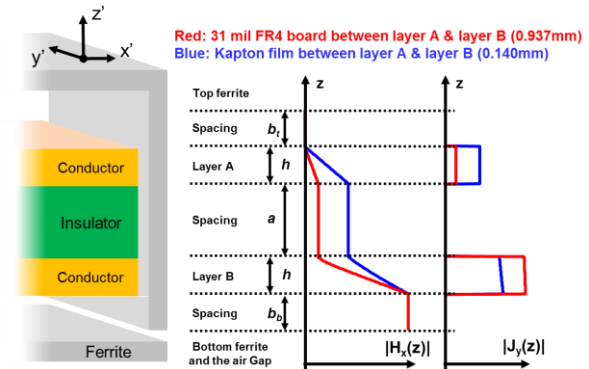
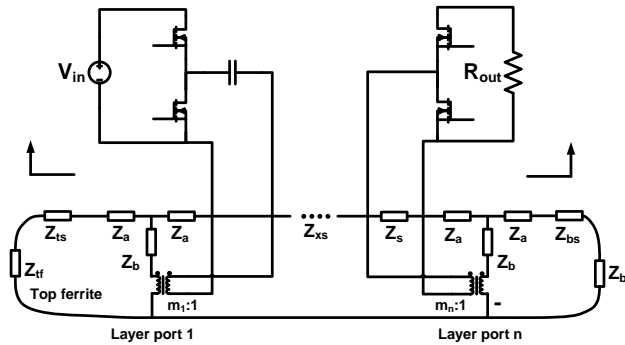


```

*-----Netlist for a single layer-----
*-----1. Describing the Impedances-----
*--Name---Node 1-----Node 2-----Value-----
R1      A      B      real(Z_a)
L1      B      C      imag(Z_a)/omega
L2      C      D      real(Z_a)
R2      D      E      imag(Z_a)/omega
R3      C      F      real(Z_a)
L3      F      G      imag(Z_a)/omega
*-----2. Describing the ideal transformer-----
LA      I      J      d^2
LB      G      H      1
K      LA     LB     1
    
```

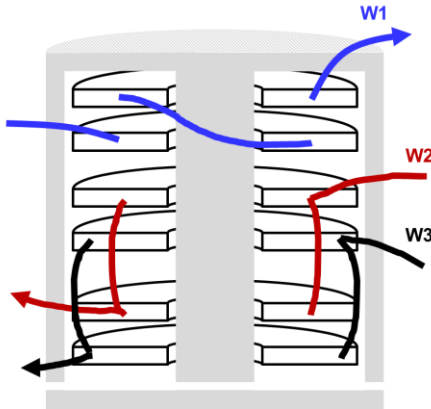


→ “Magnetics-in-the-Loop” Simulations → Visualizing H_x, E_y, J_y , just as in FEM

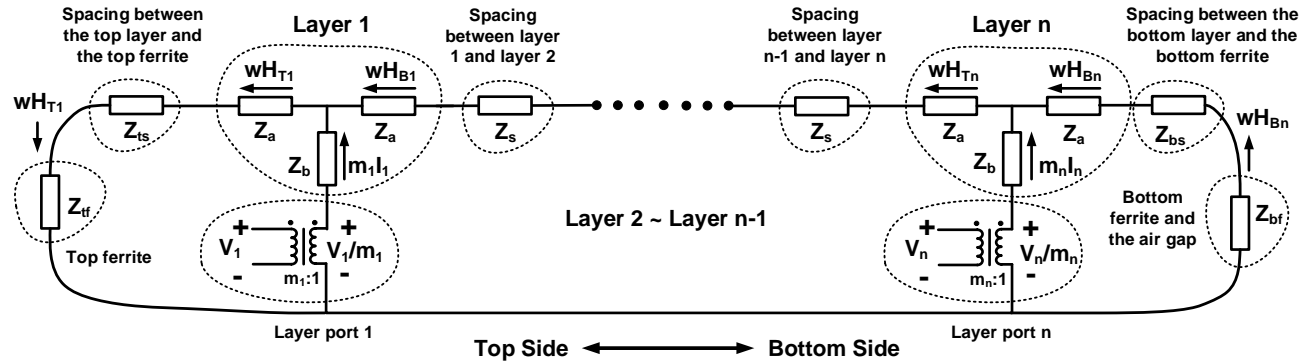


Use Python/Matlab scripts to rapidly generate the netlist ~ ~
Use SPICE to rapidly solve the netlist ~ ~
A GUI is under development ~ ~

Physical Structure



Modular Layer Model (SPICE netlist)



Simplify

Parameter Extractions Using:

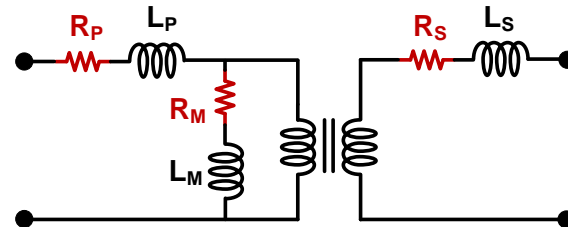
Open and Short Circuit Simulations.

- Impedance Matrix

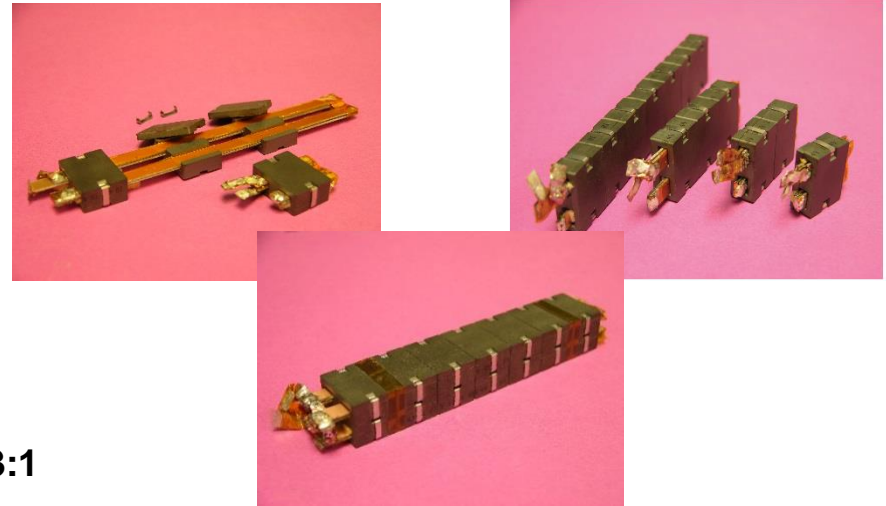
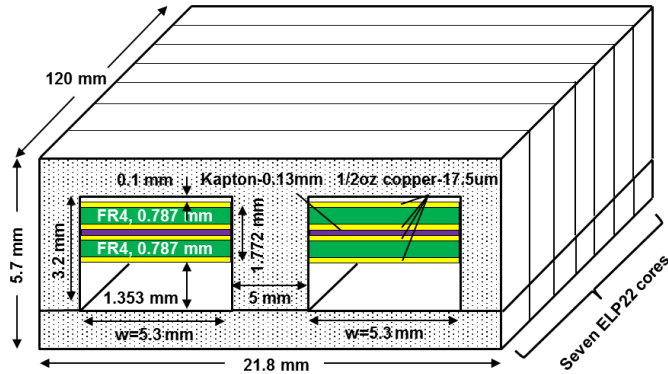
$$V_{N \times 1} = Z_{N \times N} \times I_{N \times 1}$$

- Extract Parameters for Other Circuit Models.

Conventional Transformer T Model:

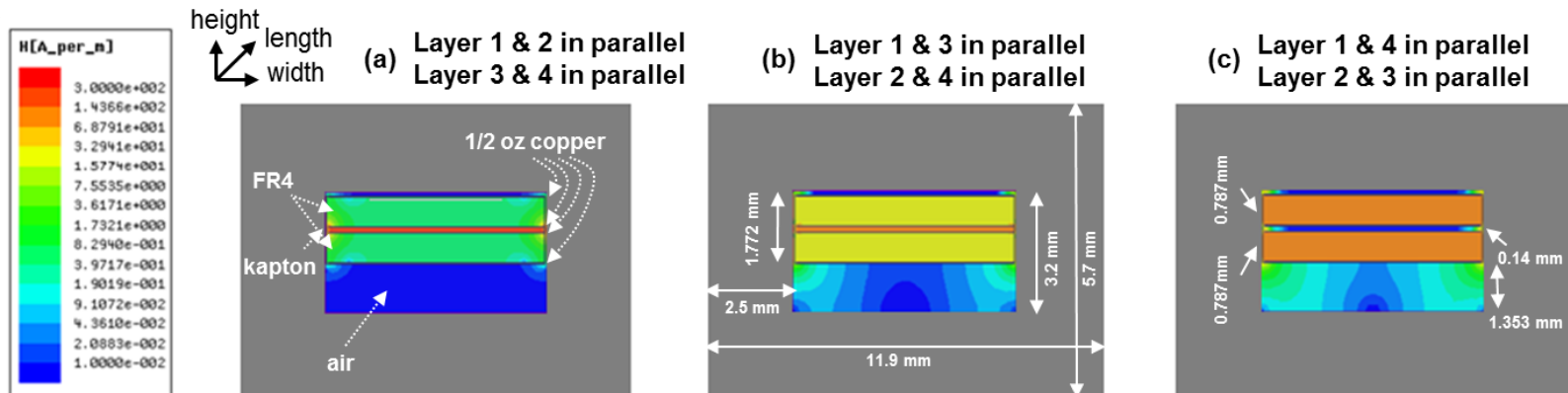


Experimental Measurements

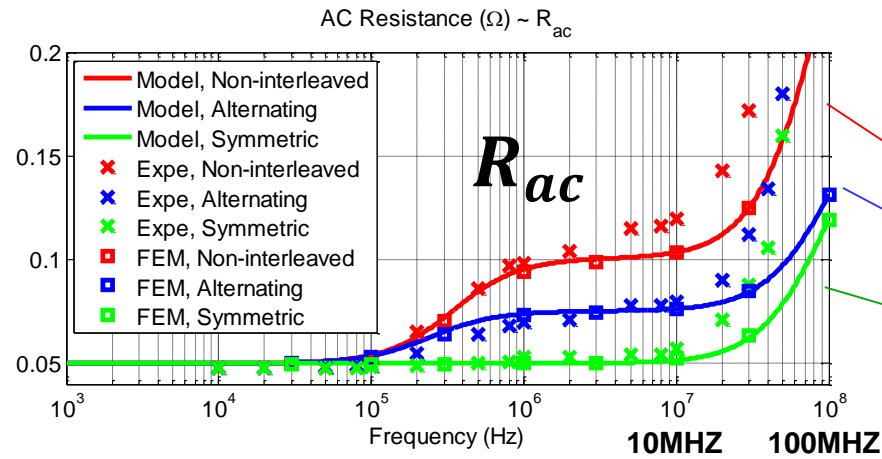
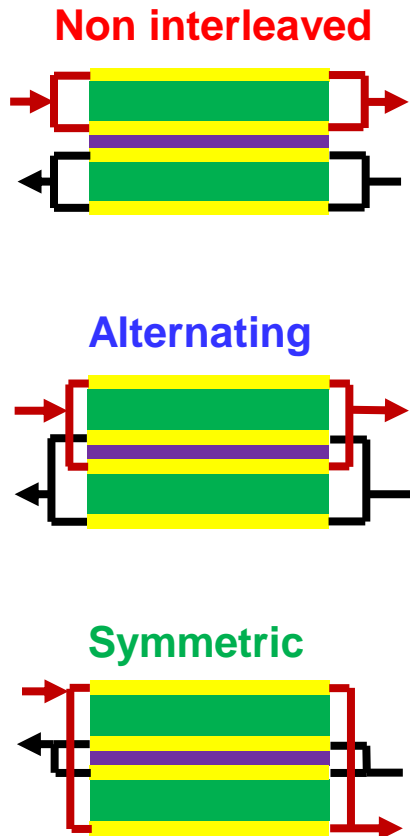


ELP22 Cores: window width/height ratio ~ 3:1

ANSYS Maxwell FEM Simulations



Comparing the P_{ac} and E_{ac} of three 1:1 transformers with three different interleaving patterns

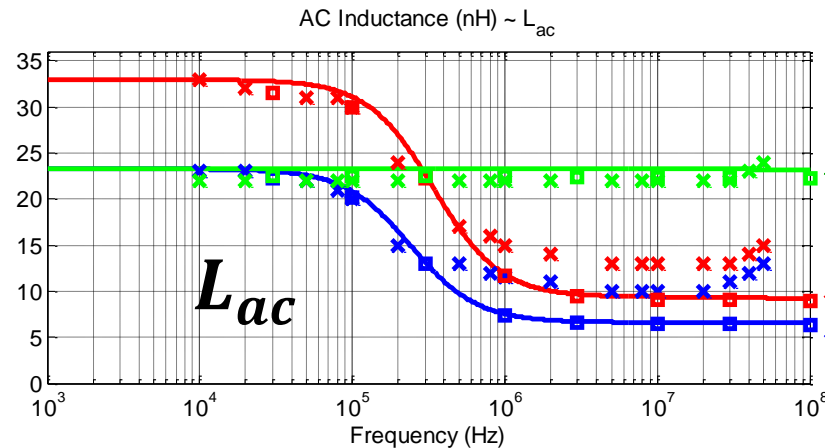


$$P_{ac} = \sum I^2 R_{ac}$$

Non Interleaved

Alternating

Symmetric



$$E_{ac} = \frac{1}{2} \sum I^2 L_{ac}$$

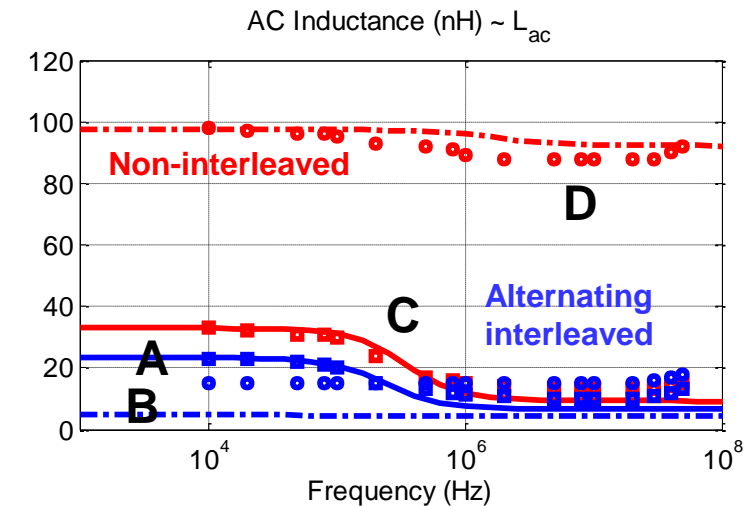
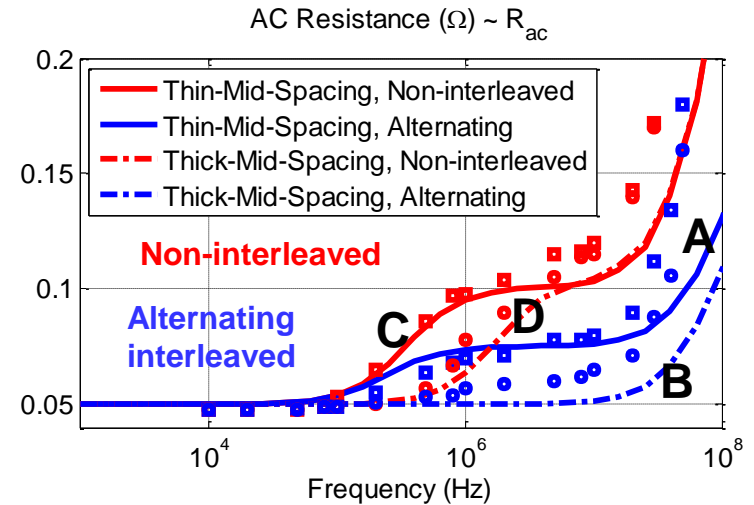
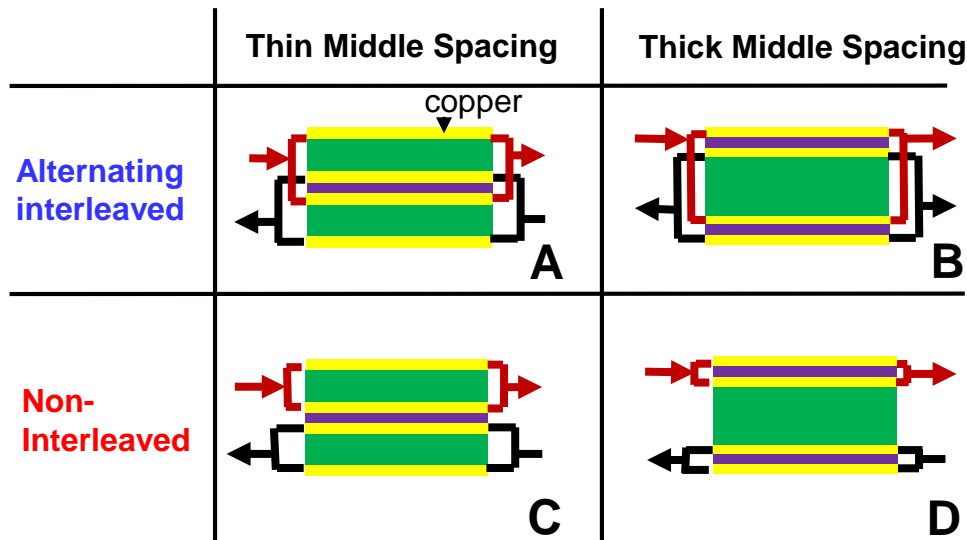
Symmetric

Non interleaved

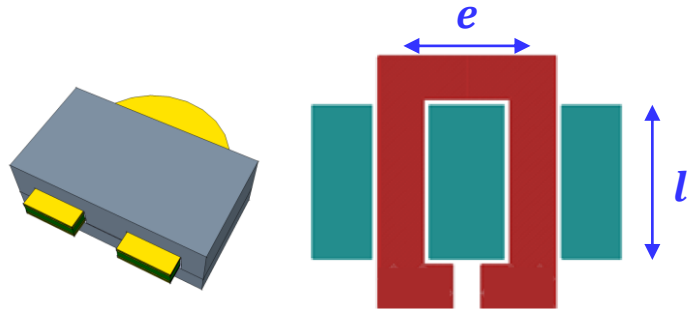
Alternating

Interleaving has to be done in the right way !!!

Impacts of PCB Layer Stacks

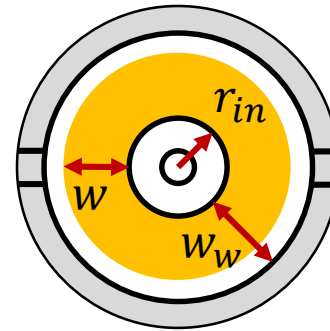


1. Quantifying the impacts of PCB stacks on impedances.
2. Choosing the optimal combination of interleaving strategies and PCB layer stacks/materials.



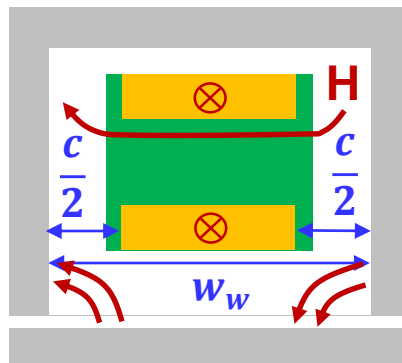
$(e/(2l+e) < 25\%, \text{ err} < 15\%)$

(a) End effects



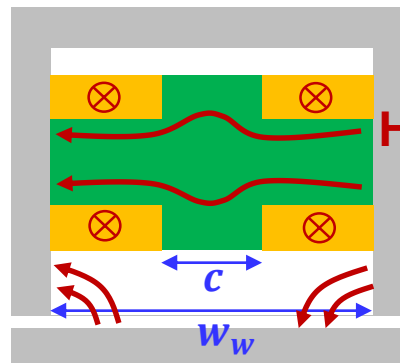
$$w_e = r_{in} \ln \frac{r_{in} + w}{r_{in}}$$

(b) Radius effects for pot cores



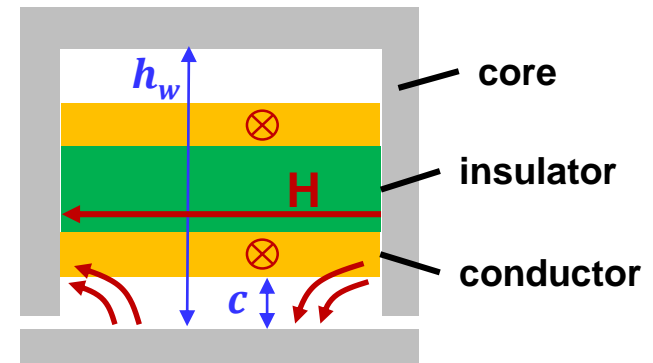
$(c/h_w < 40\%, \text{ err} < 10\%)$

(c) Conductor to core clearances (side spacing)



$(c/w_w < 40\%, \text{ err} < 10\%)$

(d) Conductor to Conductor clearances (middle spacing)



$(c/h_w > 40\%, \text{ err} < 10\%)$

(e) Fringing effects

Geometry + Operating Frequency

MQS Maxwell's Equations & 1-D Assumption

Lumped Circuit Model

Simulations (SPICE)

Numerical

1. Circuit Simulation
2. Field Visualization

Applications

1. Multiple primary/secondary windings
2. Interleaving
3. PCB Spacing
4. Board Materials
5. Other design options

Circuit Theory

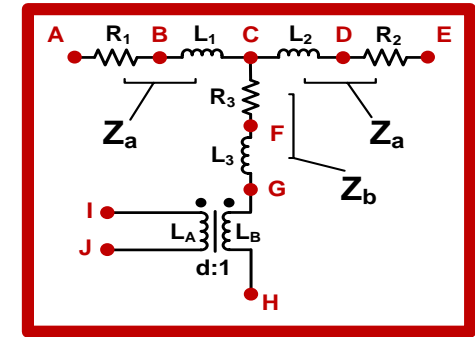
Analytical

1. Impedance matrix
2. Impedance-based cantilever model

Please check the reference for more details include:

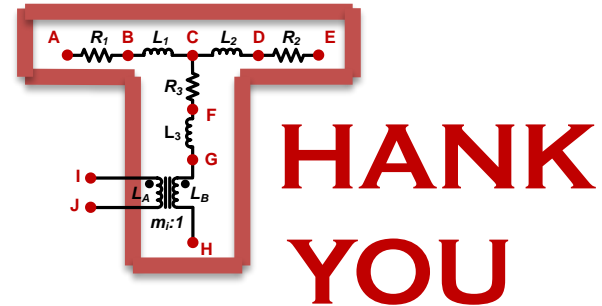
Derivations & Verifications

Empirical Design Rules



Acknowledgement:

Prof. David J. Perreault
Prof. Jeffrey H. Lang
Prof. Khurram K. Afridi
Prof. Charles R. Sullivan
Mohammad Araghchini



Sponsorship: MIT CICS, Texas Instruments

Reference:

- M. Chen, M. Araghchini, K.K. Afridi, J.H. Lang, C.R. Sullivan, and D.J. Perreault, “A Systematic Approach to Modeling Impedances and Current Distribution in Planar Magnetics,” *Proc. of the IEEE Workshop on Control and Modeling for Power Electronics (COMPEL)*, June 2014.